

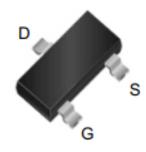
SSC8229GS6A

P-Channel Enhancement Mode MOSFET

> Features

V _{DS}	V _{GS}	R _{DS(ON)} Typ.	ID
		21mΩ@-4V5	
-20V	\pm 12V	30mΩ@-2V5	-9A
		44mΩ@-1V8	

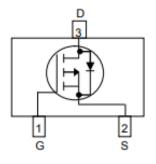
Pin configuration



SOT-23-3L

> Description

The SSC8229GS6A is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent RDSON with low gate charge. This device is suitable for use in load switch, electronic cigarette and Battery Isolation.



> Applications

- Load Switch
- Electronic Cigarette
- Battery Isolation

> Ordering Information

Device	Package	Shipping
SSC8229GS6A	SOT-23-3L	3000/Reel

Pin Configuration (Top View)



<u>Marking</u>



Symbol	Parameter	Ratings	Unit
Vdss	Drain-to-Source Voltage	-20	V
V _{GSS}	Gate-to-Source Voltage	±12	V
lo	Continuous Drain Current ^a	-9	А
I _{DM}	Pulsed Drain Current ^b	-36	A
PD	Power Dissipation ^c	2.72	W
TJ	Operation junction temperature	-55~150	°C
Tstg	Storage temperature range	-55~150	°C

> Absolute Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise noted)

➤ Thermal Resistance Ratings (T_A=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
Reja	Junction-to-Ambient Thermal Resistance ^a	46	°C/W

Note:

- a. The value of R_{θJA} is measured with the device mounted on 1 in² FR-4 board with 2oz.copper, in a still air environment with T_A=25 °C.The value in any given application depends on the user is specific board design. The power dissipation is based on the t≤10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on $T_{J(MAX)}=150$ °C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.



SSC8229GS6A

> Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = -250 \mu A$	-20			V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 uA$	-0.4	-0.7	-1	V
		V_{GS} = -4.5V, I_{D} = -5A		21	28	
Drain-Source On-Resistance	$R_{\text{DS(on)}}$	V_{GS} = -2.5V, I_D = -3A		30	39	mΩ
		V _{GS} = -1.8V, I _D = -2A		44	60	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = -16V, V_{GS} = 0V			-1	μA
Gate-Source Leak Current	lgss	$V_{GS} = \pm 12V$, $V_{DS} = 0V$			±100	nA
Transconductance	G _{FS}	V _{DS} = -10V, I _D = -5A		9		s
Forward Voltage	V _{SD}	$V_{GS} = 0V$, $I_S = -2A$			-1.3	V
Input Capacitance	Ciss			1900		
Output Capacitance	Coss	$V_{DS} = -10V, V_{GS} = 0V,$		200		pF
Reverse Transfer Capacitance	C _{RSS}	f = 1MHz		180		
Turn-on Delay Time	T _{D(ON)}			32		
Rise Time	Tr	$V_{GS} = -4.5V, V_{DS} = -10V,$		28		
Turn-off Delay Time	T _{D(OFF)}	$R_{L} = 6\Omega, R_{G} = 3\Omega,$		128		ns
Fall Time	T _f	I _D =-1A		84		
Total Gate Charge	Q_{G}			21		
Gate to Source Charge	Q _{GS}	$V_{GS} = -4.5V, V_{DS} = -15V,$		3.8		nC
Gate to Drain Charge	Q_{GD}	I _D = -7.5A		4.8		



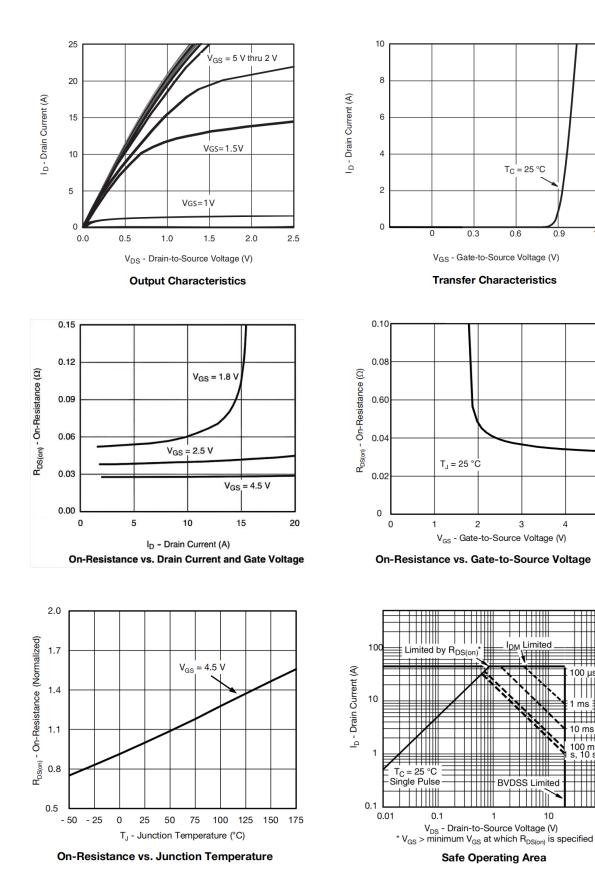
1.2

5

ms

10 ms 100 ms s. 10 s

Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

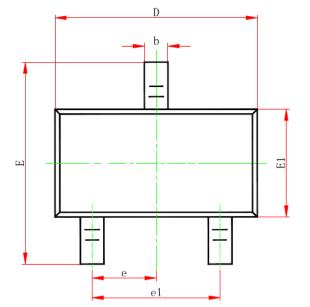


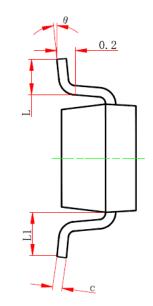
100

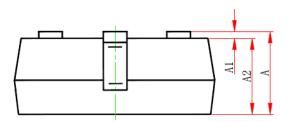


SSC8229GS6A

Package Information







Package: SOT-23-3L

Sumb a l	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
L1	0.600REF.		0.024REF.		
θ	0°	8°	0°	8°	



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